NSN 5961-01-023-3458

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Diode Semiconductor Device - Page 1 of 1



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View Online at https://aerobasegroup.com/nsn/5961-01-023-3458
Inclosure Material:
Glass
Overall Length:
Between 0.140 inches and 0.250 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.065 inches and 0.150 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
1000.0 working peak reverse voltage, peak total value and 1000.0 reverse voltage, instantaneous
Current Rating Per Characteristic:
25.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 uninsulated wire lead
Specification Data:
81349-mil-s-19500/286 government specification
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: